S/N Unknown

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Stephen Y. Chou

Examiner: Unknown

Serial No.:

Unknown

Group Art Unit: Unknown

Filed:

Herewith

Docket: 600.426US2

Title:

IMPROVED RELEASE SURFACES, PARTICULARLY FOR USE IN

NANOIMPRINT LITHOGRAPHY

INFORMATION DISCLOSURE STATEMENT

Box Patent Application Commissioner for Patents Washington, D.C. 20231

In compliance with the duty imposed by 37 C.F.R. § 1.56, and in accordance with 37 C.F.R. §§ 1.97 et. seq., the enclosed materials are brought to the attention of the Examiner for review in connection with the above-identified patent application. Pursuant to the provisions of MPEP 609, Applicant requests that a copy of the 1449 form, initialed as being considered by the Examiner be returned to the Applicant.

In accordance with 37 C.F.R. §1.98(d), copies of the listed documents are not provided as these references were previously cited by or submitted to the U.S. Patent Office in connection with Applicant's prior U.S. application, Serial No. 09/107,006, filed on June 30, 1998, which is relied upon for an earlier filing date under 35 U.S.C. §120.

Applicant respectfully request consideration of these references during prosecution of the above-identified matter. The Examiner is invited to contact the Applicant's Representative at the below-listed telephone number if there are any questions regarding this communication.

Respectfully submitted,

STEPHEN Y. CHOU

By his Representatives,

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Gary J. Speier Reg. No. 45,458

Express Mail" mailing label number: EL873861011US

Form 1449* INFORMATION DISCLOSURE STATEMENT BY APPLICANT (Use several sheets if necessary)			Atty, Docket No.: 600.426US2		Serial No. Unknown				
			Applicant: Stephen Y. Chou						
			Filing Date: Herewith		Group: Unknown				
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Examiner

*Substitute Disclosure Statement Form (PTO-1449)

Date Considered

⁻⁻ EXAMINER: Initial if citation considered, whether or not citation is in conformance with most 609; fraw line through citation if not in conformance and not considered. Include copy of this form with dext communication to applicant.

		Sheet 2 of *P*		
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^{*}Substitute Disclosure Statement Form (PIO-1449)

^{**}EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.